

^{oN Semiconductor®} FSA2466 DATA / AUDIO Low-Voltage Dual DPDT Analog Switch

Features

Sw itch Type	DPDT (2x)
Input Type	Data / Audio Switch
Input Signal Range	0 to V _{CC}
Vcc	1.65 to 4.45 V
R _{ON}	2.5 Ω at 2.7 V
R _{FLAT}	0.8 Ω at 2.7 V
ESD	8 kV HBM
Bandw idth	245 MHz
C _{ON} at 240MHz	16 pF
C _{OFF} at 240MHz	6.0 pF
Features	Low Icct
Package	16- Lead UMLP 1.80 x 2.60 x 0.55 mm, 0.40 mm pitch
Top Mark	KA
Ordering Information	FSA2466UMX

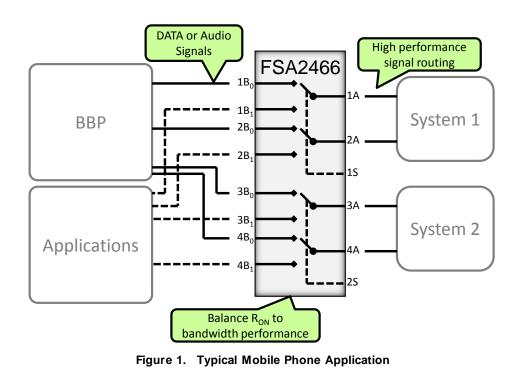
Description

The FSA2466 is a dual Double-Pole, Double-Throw (DPDT) analog switch. The FSA2466 operates from a single 1.65 V to 4.45 V supply and features an ultra-low on resistance of 2 Ω at a +2.7 V supply and T_A=25°C. This device is fabricated with sub-micron CMOS technology to achieve fast switching speeds and is designed for break-before-make operation.

FSA2466 features very low quiescent current even when the control voltage is lower than the V_{CC} supply. This allows mobile handset applications direct interface with the baseband processor general-purpose VOs.

Applications

- MP3 Portable Media Players
- Cellular Phones, Smartphones



Pin Configuration

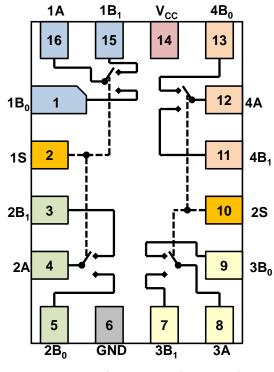


Figure 2. FSA2466UMX (Top View)

Pin Descriptions

Pin #	Name	Туре	Description						
1	1B ₀	VO	Data / Audio Port						
2	1S	Input	Control Input for Data & Common Ports 1 & 2	0 $1B_0 = 1A \& 2B_0 = 2A$					
2	15	liput	Control input for Data & Control Ports 1 & 2	1 $1B_1 = 1A \& 2B_1 = 2A$					
3	2B1	٧O	Data / Audio Port	· ·					
4	2A	٧O	Data / Audio Common Port						
5	2B ₀	VO	Data / Audio Port						
6	GND	GND							
7	3B1	VO	Data / Audio Port						
8	ЗA	٧O	Data / Audio Common Port						
9	3B0	VO	Data / Audio Port						
10	2S	Input	Control Input for Data & Common Ports 3 & 4 0 $3B_0 = 3A & 4B_0 = 4$						
10	20	liput	1 $3B_1 = 3A & 4B_1 = 4A$						
11	4B1	٧O	Data / Audio Port						
12	4A	٧O	Data / Audio Common Port						
13	4B ₀	٧O	Data / Audio Port						
14	Vcc	Supply	Voltage supply						
15	1B ₁	VO	Data / Audio Port						
16	1A	٧O	Data / Audio Common Port						

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
Vcc	Supply Voltage	-0.50	5.25	V	
Vs	Sw itch Voltage		-0.5	V _{CC} +0.3	V
V _{IN}	Input Voltage		-0.5	5.0	V
lıк	Input Diode Current		-50		mA
lsw	Sw itch Current		350	mA	
ISWPEAK	Peak Switch Current (Pulsed at 1ms Duration		500	mA	
T _{STG}	Storage Temperature Range	-65	+150	٥C	
TJ	Junction Temperature			+150	٥C
TL	Lead Temperature, Soldering 10 Seconds			+260	٥C
		VO to GND		8	kV
ESD	Human Body Model, JESD22-A114	Pow er to GND		8	
ESD			8	κV	
	Charge Device Model, JEDEC: JESD22-C101		2		

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
Vcc	Supply Voltage ⁽¹⁾	1.65	4.45	V
V _{IN}	Control Input Voltage ⁽²⁾	0	Vcc	V
Vs	Switch Input Voltage	0	Vcc	V
TA	Operating Temperature	-40	+85	٥C

Note:

1. For 4.45 V operation, SEL frequency (pins 1S & 2S) should not exceed 100Hz and 100ns edge rate.

2. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Typical values are at $T_A=25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Condition	V _{cc} (V)	T _A =+25°C			T _A =-40 to +85⁰C		Unit
			,	Min.	Тур.	Max.	Min	Max.	
			4.30				1.4		
N/	han it Maltana I Kali		2.70 to 3.60				1.3		
VIH	Input Voltage High		2.30 to 2.70				1.1		V
			1.65 to 1.95				0.9		
			4.30					0.7	
M.	Input Voltago Low		2.70 to 3.60					0.5	V
VIL	Input Voltage Low		2.30 to 2.70					0.4	v
			1.65 to 1.95					0.4	
l _{IN}	Control Input Leakage	$V_{IN}=0$ V to V_{CC}	1.65 to 4.30				-0.5	0.5	μA
	Off Leakage Current of Port nB_0 and nB_1	nA=0.3 V, V _{CC} -0.3 V					-50	50	
NO(OFF) NC(OFF)		$\begin{array}{l} nB_0 \text{ or } nB_1 = 0.3 \ \text{V}, \\ \text{V}_{CC} - 0.3 \ \text{V} \text{ or} \\ \text{Floating} \end{array}$	1.95 to 4.30	-10		10			nA
	On Leakage Current of Port A	nA=0.3 V, V _{CC} -0.3V							
I _{A(ON)}		$\begin{array}{l} nB_0 \text{ or } nB_1 = 0.3 \ V, \\ V_{CC} - 0.3 \ V \text{ or} \\ Floating \end{array}$	1.95 to 4.30	-10		10	-50	50	nA
		l _{OUT} =100 mA	4.30		1.6			2.0	
		$I_{OUT}=100 \text{ mA}, \text{ nB}_0$	2.70		2.0			2.5	
Ron	Switch On Resistance ⁽ 3 ⁾	or nB ₁ =0 V, 0.7 V, 1.2 V, V _{CC}	2.30		2.2			2.7	Ω
		I_{OUT} =100mA, nB ₀ or nB ₁ =0.7 V	1.80		4.3			6.0	
A Davi	On Resistance Matching	I_{OUT} =100 mA, nB ₀ or nB ₁ =0.8 V	2.70		0.04			0.20	0
ΔR_{ON}	Betw een Channels ⁽⁴⁾	I_{OUT} =100 mA, nB ₀ or nB ₁ =0.7 V	2.30		0.03			0.30	Ω
D	On Resistance Flatness ⁽⁵⁾	l _{OUT} =100 mA, nB₀	2.70		0.60			0.8	_
RFLAT(ON)	On Resistance Flathess 3	or $nB_1 = 0V \rightarrow V_{CC}$	2.30		0.75			0.9	Ω
lcc	Quiescent Supply Current	V _{IN} =0 V to V _{CC} , I _{OUT} =0 V	4.30	-100		100	-500	500	nA
loc-	Increase in I _{CC} Current	V _{IN} =1.8 V	4.30		7	12		15	
Ісст	per Control Voltage	V _{IN} =2.6 V	4.30		3	6		7	μA

Notes:

3. On resistance is determined by the voltage drop between the A and B pins at the indicated current through the switch.

4. $\Delta R_{ON} = R_{ON max} - R_{ON min}$ measured at identical V_{CC}, temperature, and voltage.

5. Flatness is defined as the difference between the maximum and minimum value of on resistance over the specified range of conditions.

AC Electrical Characteristics

Typical values are at $T_A=25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Condition	V _{cc}	Т	_A =+25 ⁰	2c	T _A =-40 t	to +85⁰C	Unit	Figure
Symbol			• 66	Min.	Тур.	Max.	Min.	Max.		
			3.6 to 4.3			50		60		
t _{ON}	Turn-On Time	nB ₀ or nB ₁ =1.5 V R _L =50 Ω, C _L =35 pF	2.7 to 3.6			65		75	ns	Figure 3
			2.3 to 2.7			80		90		
			3.6 to 4.3			32		40		
toff	Turn-Off Time	nB ₀ or nB ₁ =1.5 V R _L =50 Ω, C _L =35 pF	2.7 to 3.6			42		50	ns	Figure 3
		1400 II, 000 pi	2.3 to 2.7			52		60		
			3.6 to 4.3		15					
t _{BBM}	Break-Before- Make Time ⁽ 6 ⁾	nB ₀ or nB ₁ =1.5 V R _L =50 Ω, C _L =35 pF	2.7 to 3.6		15				ns	Figure 4
			2.3 to 2.7		15					
		CL=100 pF, V _{GEN} =0 V, R _{GEN} =0 Ω	3.6 to 4.3		8				pC	
Q	Charge Injection	CL=100 pF, V _{GEN} =0 V, R _{GEN} =0 Ω	2.7 to 3.6		6					Figure 6
		CL=100 pF, V _{GEN} =0 V, R _{GEN} =0 Ω	2.3 to 2.7		3					
			3.6 to 4.3		-90					
OIRR	Off Isolation	f=100 KHz, R _L =50 Ω, C _L =5 pF	2.7 to 3.6		-90				dB	Figure 5
			2.3 to 2.7		-90					
			3.6 to 4.3		-90					
Xtalk	Crosstalk	f=100 KHz, R _L =50 Ω, C _L =5 pF	2.7 to 3.6		-90				dB	Figure 5
		0L=0 pi	2.3 to 2.7		-90					
BW	-3dB Bandwidth	RL=50 Ω	2.3 to 4.3		245				MHZ	Figure 8
			3.6 to 4.3		0.21					
		R _L =32 Ω, V _{IN} =2V _{PP} , f=20 to 20 kHZ	2.7 to 3.6		0.17				%	
	Total Harmonic		2.3. to 2.7		0.26					
THD	Distortion	RL=600 Ω,	3.6 to 4.3		0.01					Figure 9
		V _{IN} =2 V _{PP} ,	2.7 to 3.6		0.008					
		f=20 to 20 kHZ	2.3. to 2.7		0.012					

Note:

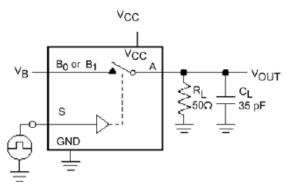
6. Guaranteed by characterization, not production tested.

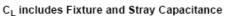
Capacitance

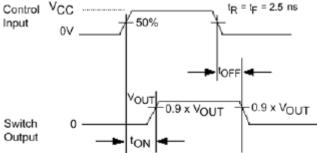
Symbol	Parameter	Condition	V _{cc}	T _A =+25⁰C Typical	Unit	Figure	
C _{IN}	Control Pin Input Capacitance	f=1 MHz	0	1.3	pF	Figure 3	
COFF	B Port Off Capacitance	f=1 MHz	3.3	6.0	рF	Figure 3	
OOFF	Bron on oppositione		f=240 MHz	3.3	6.0	рі	rigure 5
Con	A Port On Capacitance	f=1 MHz	3.3	21.0	рF	Figure 3	
CON	A Port On Capacitance	f=240 MHz	3.3	16.0	рі	rigure 5	

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AC Loadings and Waveforms

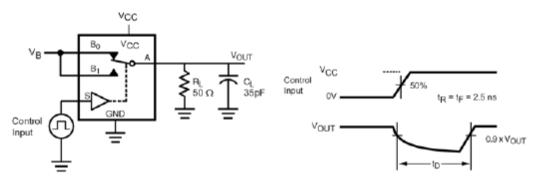






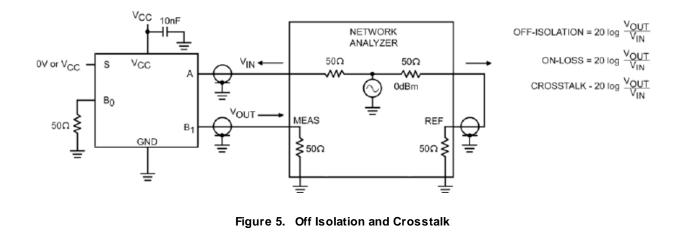
Logic Input Waveforms Inverted for Switches that have the Opposite Logic Sense

Figure 3. Turn-On / Turn-Off Timing

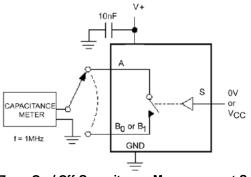


CL Includes Fixture and Stray Capacitance





AC Loadings and Waveforms (Continued) ΔV_{OUT} Vcc VOUT RGEN А Vout B₀ or B₁ c_{L} IN VGE OFF OFF ON GND ╧ Control ON OFF OFF Input IN $Q = (\Delta V_{OUT})(C_L)$ Figure 6. **Charge Injection** ٧+ 10nF s 0V or CAPACITANCI



On / Off Capacitance Measurement Setup Figure 7.

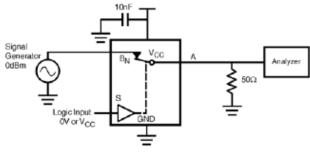


Figure 8. **Bandwidth**

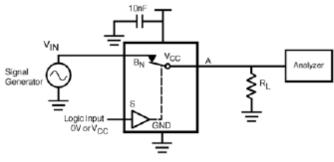
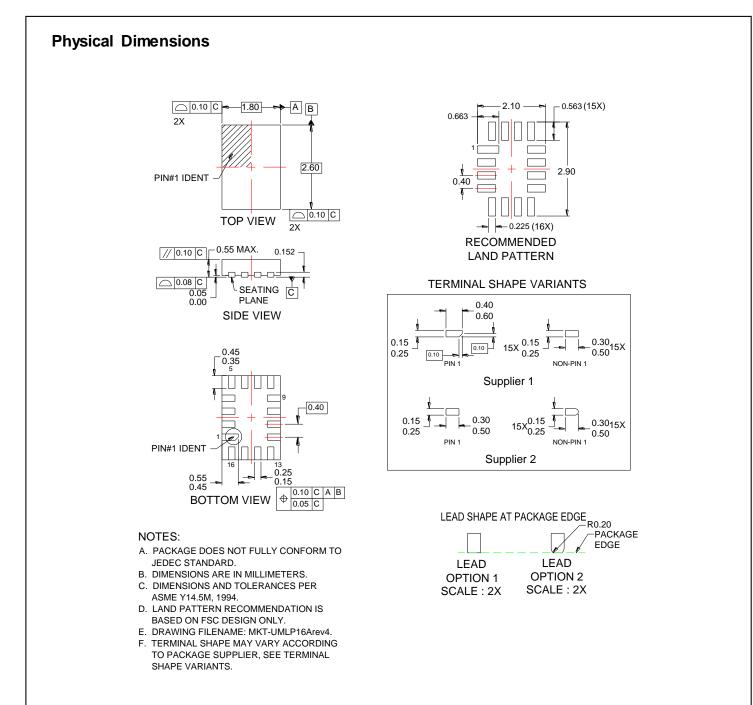


Figure 9. Harmonic Distortion





Order Number	Operating Temperature Range	Package Description	Packing Method
FSA2466UMX	-40 to 85°C	16-Terminal Ultrathin Molded Leadless Package	Tape & Reel

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